

GTM CORPORATION

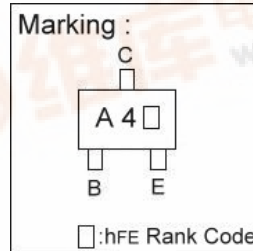
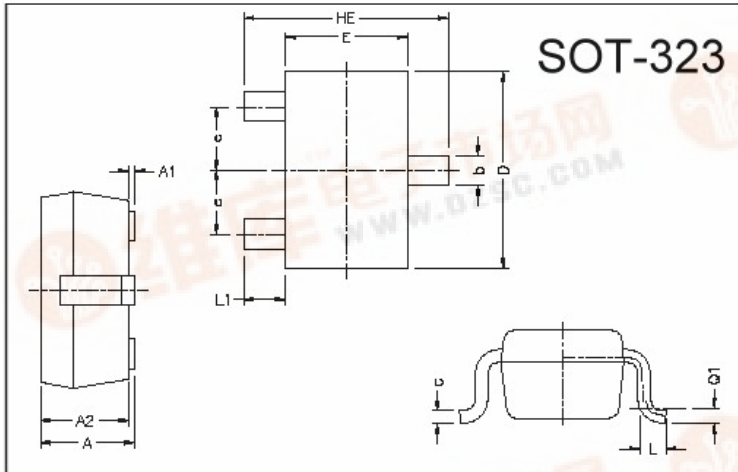
ISSUED DATE :2004/12/08
REVISED DATE :

GSMBT1015 PNP EPITAXIAL PLANAR TRANSISTOR

Description

The GSMBT1015 is designed for use in driver stage of AF amplifier and general purpose amplification.

Package Dimensions



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	0.80	1.10	L1	0.42 REF.	
A1	0	0.10	L	0.15	0.35
A2	0.80	1.00	b	0.25	0.40
D	1.80	2.20	c	0.10	0.25
E	1.15	1.35	e	0.65 REF.	
HE	1.80	2.40	Q1	0.15 BSC.	

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Ratings	Unit
Junction Temperature	Tj	+150	°C
Storage Temperature	Tstg	-55~+150	°C
Collector to Base Voltage	VCBO	-50	V
Collector to Emitter Voltage	VCEO	-50	V
Emitter to Base Voltage	VEBO	-5	V
Collector Current	IC	-150	mA
Total Power Dissipation	PD	225	mW

Characteristics at Ta = 25°C

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BVCBO	-50	-	-	V	IC=-100uA
BVCEO	-50	-	-	V	IC=-1mA
BVEBO	-5	-	-	V	IE=-10uA
ICBO	-	-	-100	nA	VCB=-50V
IEBO	-	-	-100	nA	VEB=-5V
*VCE(sat)	-	-	-300	mV	IC=-100mA, IB=-10mA
*VBE(sat)	-	-	-1.1	V	IC=-100mA, IB=-10mA
*hFE1	120	-	700		VCE=-6V, IC=-2mA
*hFE2	25	-	-		VCE=-6V, IC=-150mA
fT	80	-	-	MHz	VCE=-10V, IC=-1mA, f=100MHz
Cob	-	-	7	pF	VCB=-10V, f=1MHz, IE=0

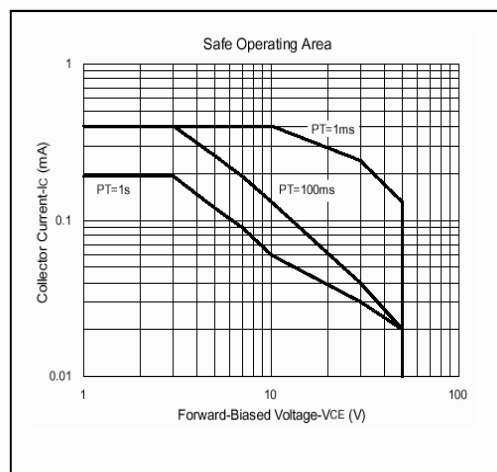
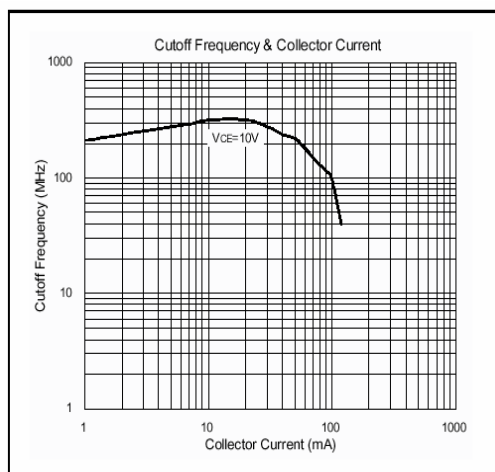
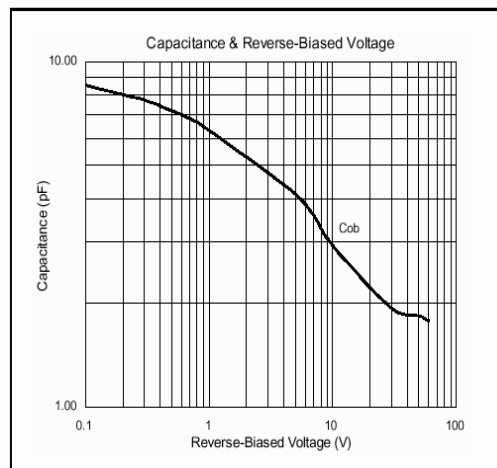
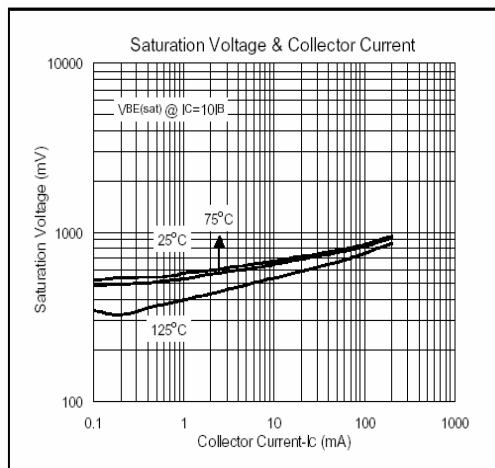
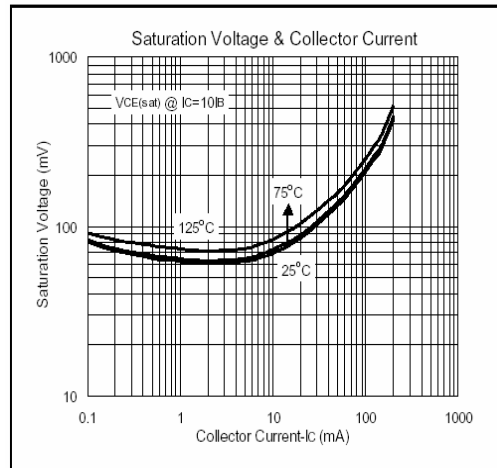
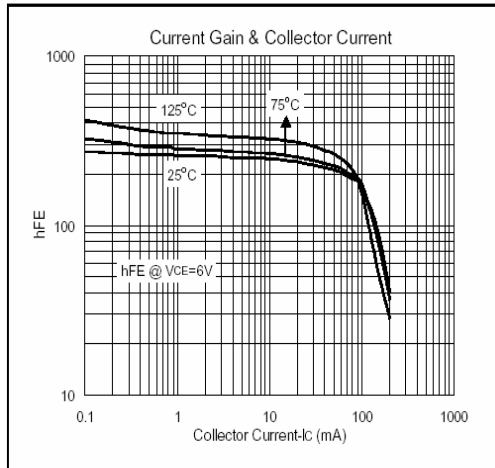
* Pulse Test: Pulse Width ≤ 380us, Duty Cycle ≤ 2%

Classification Of hFE1

Rank	A4Y	A4G	A4B
Range	120-140	200-400	350-700



Characteristics Curve



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